BF421, BF423

High Voltage Transistors

PNP Silicon

Features

 These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	BF421	BF423	Unit
Collector - Emitter Voltage	V _{CEO}	-300	-250	Vdc
Collector - Base Voltage	V _{CBO}	-300	-250	Vdc
Emitter - Base Voltage	V _{EBO}	-5.0		Vdc
Collector Current – Continuous	Ic	-500		mAdc
Collector Current - Peak	I _{CM}	10	00	mA
Total Device Dissipation (Note 1) @ T _A = 25°C Derate above 25°C	P _D	830 6.6		mW mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to	+150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	150	°C/W
Thermal Resistance, Junction-to-Lead	$R_{ heta JL}$	68	°C/W

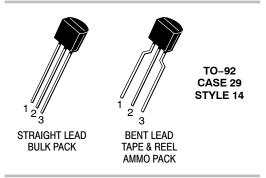
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

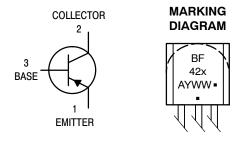
 Mounted on a FR4 board with 200 mm² of 1 oz copper and lead length of 5 mm.



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BF42x = Device Codex = 1 or 3

A = Assembly Location

Y = Year WW = Work Week • Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping
BF421ZL1G	TO-92 (Pb-Free)	2000/Ammo Pack
BF423G	TO-92 (Pb-Free)	5000 Units/Box
BF423ZL1G	TO-92 (Pb-Free)	2000/Ammo Pack

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS				•	1
Collector – Emitter Breakdown Voltage (Note 1) $(I_C = -1.0 \text{ mAdc}, I_B = 0)$	BF421 BF423	V _{(BR)CEO}	-300 -250	- -	Vdc
Collector – Base Breakdown Voltage (I _C = –100 μAdc, I _E = 0)	BF421 BF423	V _(BR) CBO	-300 -250	- -	Vdc
Emitter – Base Breakdown Voltage ($I_E = -100 \mu Adc, I_C = 0$)	BF421 BF423	V _{(BR)EBO}	-5.0 -5.0	- -	Vdc
Collector Cutoff Current (V _{CB} = -200 Vdc, I _E = 0)	BF421 BF423	I _{CBO}	- -	-0.01 -	μAdc
Emitter Cutoff Current $(V_{EB} = -5.0 \text{ Vdc}, I_C = 0)$	BF421 BF423	I _{EBO}	- -	-100 -	nAdc
ON CHARACTERISTICS					
DC Current Gain (I _C = -25 mA, V _{CE} = -20 Vdc)	BF421 BF423	h _{FE}	50 50		-
Collector – Emitter Saturation Voltage (I _C = -20 mAdc, I _B = -2.0 mAdc)		V _{CE(sat)}	-	-0.5	Vdc
Base – Emitter Saturation Voltage (I _C = -20 mA, I _B = -2.0 mA)		V _{BE(sat)}	_	-2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS			•		-
Current – Gain – Bandwidth Product (I _C = –10 mAdc, V _{CE} = –10 Vdc, f = 20 MHz)		f _T	60	-	MHz
Common Emitter Feedback Capacitance (V _{CB} = -30 Vdc, I _E = 0, f = 1.0 MHz)		C _{re}	_	2.8	pF

^{1.} Pulse Test: Pulse Width ≤ 300 μs; Duty Cycle ≤ 2.0%.

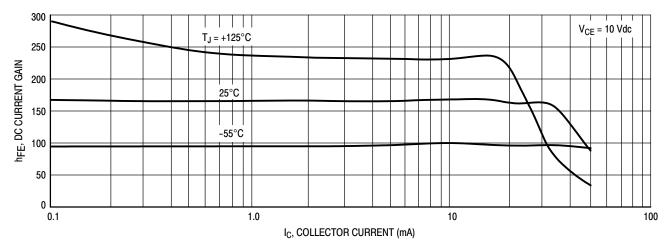
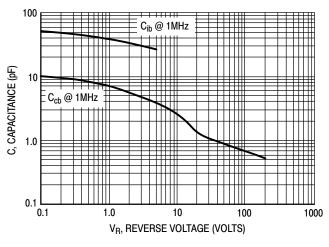


Figure 1. DC Current Gain



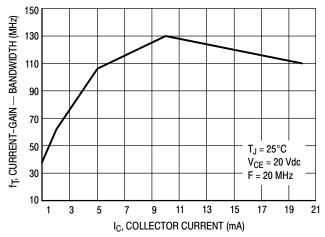
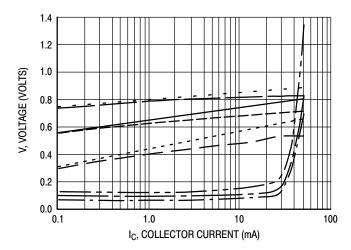


Figure 2. Capacitance

Figure 3. Current-Gain - Bandwidth



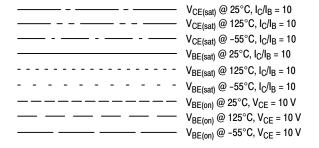


Figure 4. "ON" Voltages

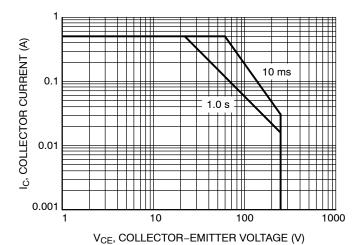
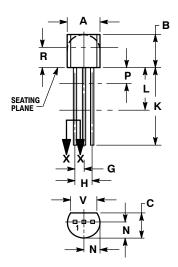


Figure 5. Safe Operating Area

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 029-11 **ISSUE AM**



STRAIGHT LEAD **BULK PACK**



BENT LEAD

TAPE & REEL AMMO PACK

NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R
- IS UNCONTROLLED.
 LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

STYLE 14:

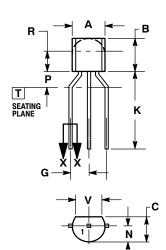
- PIN 1. EMITTER
 - 2 COLLECTOR
 - BASE 3.

NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN MAX		
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
P	1.50	4.00	

2.93





SECTION X-X

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